

# 1MHZ CMOS Rail-to-Rail IO Opamp with RF Filter

#### **Features**

Single-Supply Operation from +2.1V ~ +5.5V

• Rail-to-Rail Input / Output

• Gain-Bandwidth Product: 1MHz (Typ.)

• Low Input Bias Current: 1pA (Typ.)

• Low Offset Voltage: 3.5mV (Max.)

• Quiescent Current: 40µA per Amplifier (Typ.)

• Operating Temperature: -40°C ~ +125°C

• Embedded RF Anti-EMI Filter

Small Package:

LMV321 Available in SOT23-5 Packages

LMV358 Available in SOP-8, MSOP-8, DIP-8 Packages LMV324 Available in SOP-14 and TSSOP-14 Packages

### **General Description**

The LMV321 family have a high gain-bandwidth product of 1MHz, a slew rate of  $0.6V/\,\mu\,s$ , and a quiescent current of  $40\,\mu\,A$ /amplifier at 5V. The LMV321 family is designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for LMV321 family. They are specified over the extended industrial temperature range (-40  $^{\circ}$ C to +125  $^{\circ}$ C). The operating range is from 2.1V to 5.5V.

### **Applications**

- ASIC Input or Output Amplifier
- Sensor Interface
- Medical Communication
- Smoke Detectors

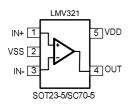
- Audio Output
- Piezoelectric Transducer Amplifier
- Medical Instrumentation
- Portable Systems

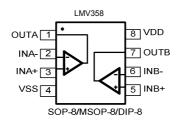
### **Ordering Information**

DEVICE	Package Type	MARKING	Packing	Packing Qty
LMV321CDBVRG	SOT23-5L	A13	REEL	3000pcs/reel
LMV321IDBVRG	SOT23-5L	A13	REEL	3000pcs/reel
LMV358CDRG	SOP8L	LMV358	REEL	2500pcs/reel
LMV358IDRG	SOP8L	LMV358	REEL	2500pcs/reel
LMV358CPG	DIP8L	LMV358	TUBE	1000pcs/box
LMV358IPG	DIP8L	LMV358	TUBE	1000pcs/box
LMV358CMMRG	MSOP8L	V358	REEL	3000pcs/reel
LMV358IMMRG	MSOP8L	V358	REEL	3000pcs/reel
LMV324CDRG	SOP14L	LMV324	REEL	2500pcs/reel
LMV324IDRG	SOP14L	LMV324	REEL	2500pcs/reel
LMV324CPWRG	TSSOP14L	LMV324	REEL	2500pcs/reel
LMV324IPWRG	TSSOP14L	LMV324	REEL	2500pcs/reel



## **Pin Configuration**





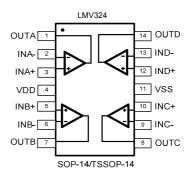


Figure 1. Pin Assignment Diagram

### **Absolute Maximum Ratings**

Condition		Min	Мах		
Power Supply Voltage (V <sub>DD</sub> to Vss)		-0.5V	+7.5V		
Analog Input Voltage (IN+ or IN-)		Vss-0.5V	V <sub>DD</sub> +0.5V		
PDB Input Voltage		Vss-0.5V	+7V		
Operating Temperature Range	LMV3xxI	-40°C	+125°C		
Operating remperature Nange	LMV3xxC	0°C	+ 70 °C		
Junction Temperature		+160°C			
Storage Temperature Range		-55°C	+150°C		
Lead Temperature (soldering, 10sec)		+26			
Package Thermal Resistance (T <sub>A</sub> =+25℃)	<u>.</u>				
SOP-8, θ <sub>JA</sub>		125°C/W			
MSOP-8, θ <sub>JA</sub>		216°C/W			
SOT23-5, θ <sub>JA</sub>		190°C/W			
ESD Susceptibility					
НВМ		6KV			
MM		300V			

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



### **Electrical Characteristics**

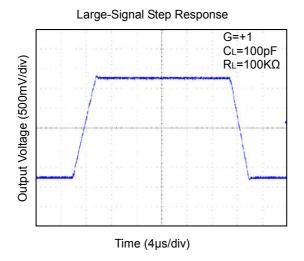
(At  $V_S$  = +5V,  $R_L$  = 100 $k\Omega$  connected to  $V_S/2$ , and  $V_{OUT}$  =  $V_S/2$ , unless otherwise noted.)

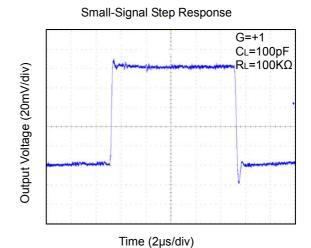
			LMV321/358/324				
PARAMETER	SYMBOL	CONDITIONS	TYP	MIN/MAX OVER TEMPERATURE			
			+25℃	+25℃	-40℃ to +85℃	UNITS	MIN/MAX
INPUT CHARACTERISTICS							
Input Offset Voltage	Vos	$V_{CM} = V_S/2$	0.4	3.5	5.6	mV	MAX
Input Bias Current	IΒ		1			pA	TYP
Input Offset Current	los		1			pA	TYP
Common-Mode Voltage Range	V <sub>CM</sub>	V <sub>S</sub> = 5.5V	-0.1 to +5.6			V	TYP
Common Mada Daigation Datio	CMDD	V <sub>S</sub> = 5.5V, V <sub>CM</sub> = -0.1V to 4V	70	62	62	dB	MINI
Common-Mode Rejection Ratio	CMRR	V <sub>S</sub> = 5.5V, V <sub>CM</sub> = -0.1V to 5.6V	68	56	55		MIN
Onen Lean Veltage Cain		$R_L = 5k\Omega$ , $V_O = +0.1V$ to +4.9V	80	70	70	dB	MINI
Open-Loop Voltage Gain	A <sub>OL</sub>	$R_L = 10k\Omega$ , $V_O = +0.1V$ to +4.9V	100	90	85		MIN
Input Offset Voltage Drift	$\Delta V_{OS}/\Delta_T$		2.7			μV/°C	TYP
OUTPUT CHARACTERISTICS							
	V <sub>OH</sub>	R <sub>L</sub> = 100kΩ	4.997	4.990	4.980	٧	MIN
Output Voltage Swing from Rail	V <sub>OL</sub>	R <sub>L</sub> = 100kΩ	3	10	20	mV	MAX
	V <sub>OH</sub>	$R_L = 10k\Omega$	4.992	4.970	4.960	V	MIN
	V <sub>OL</sub>	$R_L = 10k\Omega$	8	30	40	mV	MAX
Output Coment	I <sub>SOURCE</sub>	D 400 L 1/4/0	84	60	45	mA M	MINI
Output Current	I <sub>SINK</sub>	$R_L = 10\Omega$ to $V_S/2$	75	60	45		MIN
POWER SUPPLY							
Onerating Valtage Dange				2.1	2.5	V	MIN
Operating Voltage Range				5.5	5.5	٧	MAX
Power Supply Rejection Ratio	PSRR	$V_S = +2.5V \text{ to } +5.5V, V_{CM} = +0.5V$	82	60	58	dB	MIN
Quiescent Current / Amplifier	ΙQ		40	60	80	μA	MAX
DYNAMIC PERFORMANCE (CL	_ = 100pF)						
Gain-Bandwidth Product	GBP		1			MHz	TYP
Slew Rate	SR	G = +1, 2V Output Step	0.6			V/µs	TYP
Settling Time to 0.1%	t <sub>S</sub>	G = +1, 2V Output Step	5			μs	TYP
Overload Recovery Time		V <sub>IN</sub> ·Gain = V <sub>S</sub>	2.6			μs	TYP
NOISE PERFORMANCE							
Voltago Noiso Donoity		f = 1kHz	27			$nV/\sqrt{Hz}$	TYP
Voltage Noise Density	e <sub>n</sub>	f = 10kHz	20			$nV / \sqrt{Hz}$	TYP

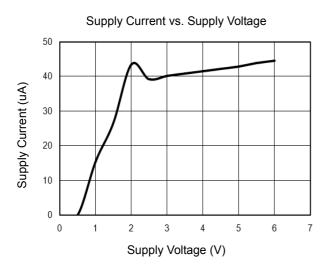


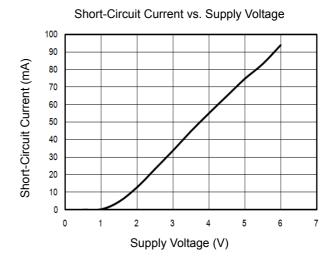
### **Typical Performance characteristics**

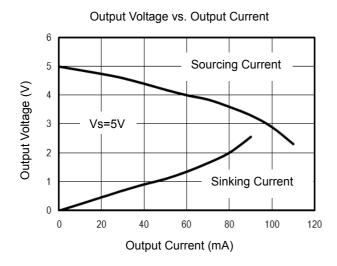
At  $T_A$ =+25°C,  $V_S$ =+5V, and  $R_L$ =100K $\Omega$  connected to  $V_S$ /2, unless otherwise noted.

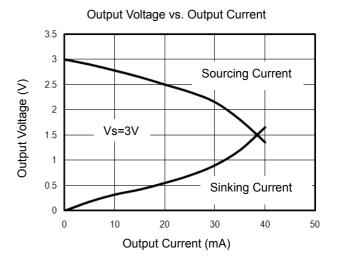








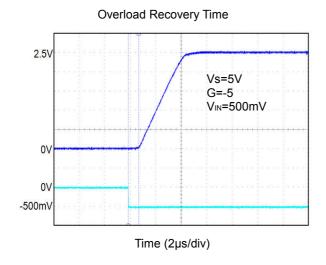


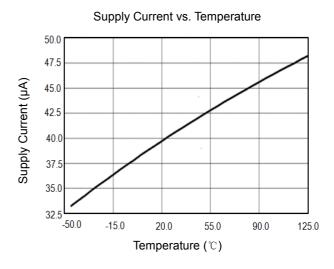


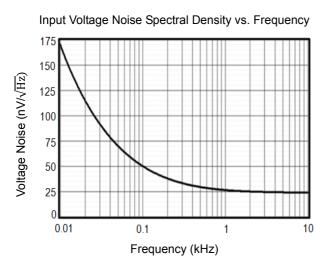


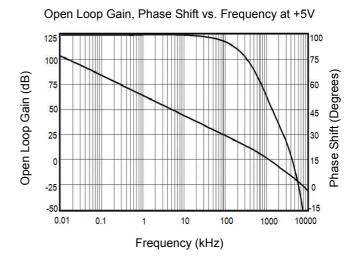
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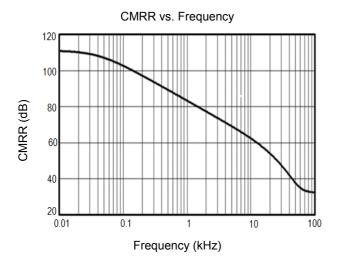
At  $T_A$ =+25°C,  $V_S$ =+5V, and  $R_L$ =100K $\Omega$  connected to  $V_S$ /2, unless otherwise noted.

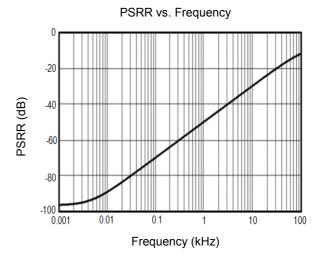














### **Application Note**

#### Size

LMV321 family series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the LMV321 family packages save space on printed circuit boards and enable the design of smaller electronic products.

### **Power Supply Bypassing and Board Layout**

LMV321 family series operates from a single 2.1V to 5.5V supply or dual  $\pm 1.05$ V to  $\pm 2.75$ V supplies. For best performance, a 0.1 $\mu$ F ceramic capacitor should be placed close to the  $V_{DD}$  pin in single supply operation. For dual supply operation, both  $V_{DD}$  and  $V_{SS}$  supplies should be bypassed to ground with separate 0.1 $\mu$ F ceramic capacitors.

#### **Low Supply Current**

The low supply current (typical 40uA per channel) of LMV321 family will help to maximize battery life. They are ideal for battery powered systems

#### **Operating Voltage**

LMV321 family operates under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime

#### Rail-to-Rail Input

The input common-mode range of LMV321 family extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### **Rail-to-Rail Output**

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of LMV321 family can typically swing to less than 5 mV from supply rail in light resistive loads (>100k $\Omega$ ), and 30mV of supply rail in moderate resistive loads (10k $\Omega$ ).

#### **Capacitive Load Tolerance**

The LMV321 family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

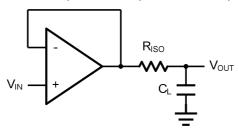


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R<sub>F</sub> provides the DC accuracy by feed-forward the V<sub>IN</sub> to R<sub>L</sub>. C<sub>F</sub>



and  $R_{\rm ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_F$ . This in turn will slow down the pulse response.

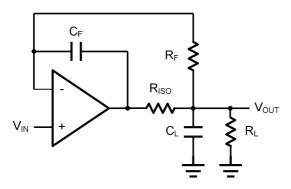


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy



### **Typical Application Circuits**

#### **Differential amplifier**

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using LMV321 family.

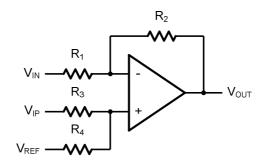


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = (\frac{R_1 + R_2}{R_2 + R_4}) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + (\frac{R_1 + R_2}{R_2 + R_4}) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. R<sub>1</sub>=R<sub>3</sub> and R<sub>2</sub>=R<sub>4</sub>), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

#### **Low Pass Active Filter**

The low pass active filter is shown in Figure 5. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_C=1/(2\pi R_3C_1)$ .

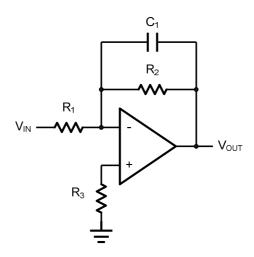


Figure 5. Low Pass Active Filter



#### **Instrumentation Amplifier**

The triple LMV321 family can be used to build a three -op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R2/R1. The two differential voltage followers assure the high input impedance of the amplifier.

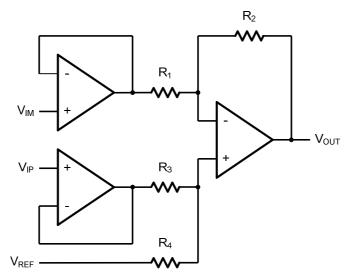


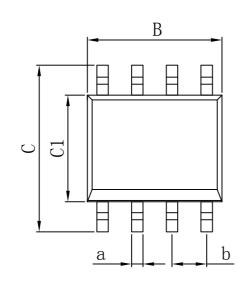
Figure 6. Instrument Amplifier

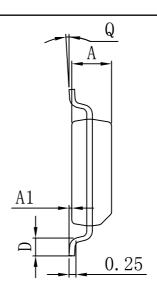


### **PACKAGE**



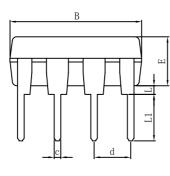
SOP8

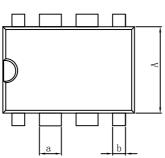




Dimensions In Millimeters							
Symbol:	Min:	Max:	Symbol :	Min:	Max:		
Α	1.225	1.570	D	0.400	0.950		
A1	0.100	0.250	Q	0°	8°		
В	4.800	5.100	а	0.420	TYP		
С	5.800	6.250	b	1.270	) TYP		
C1	3.800	4.000					

### DIP8







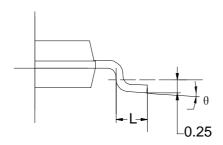
Dimensions In Millimeters							
Symbol:	Min:	Max:	Symbol :	Min :	Max:		
Α	6.100	6.680	L1	3.000	3.600		
В	9.000	9.500	а	1.524 TYP			
D	8.400	9.000	b	0.889 TYP			
D1	7.420	7.820	С	0.457	TYP		
E	3.100	3.550	d	2.540	) TYP		
L	0.500	0.700		•			

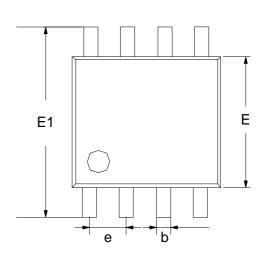


### **PACKAGE**

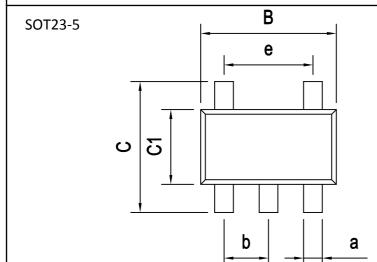
MSOP8

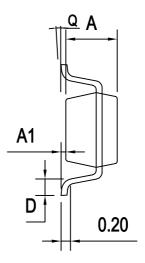






Dimensions In Millimeters							
Symbol:	Min :	Max :	Symbol :	Min :	Max:		
Α	0.800	1.200	E1	4.700	5.100		
A1	0	0.200	L	0.410	0.650		
A2	0.760	0.970	θ	0°	6°		
D	2.900	3.100	b	0.300 TYP			
E	2.900	3.100	е	0.650 TYP			

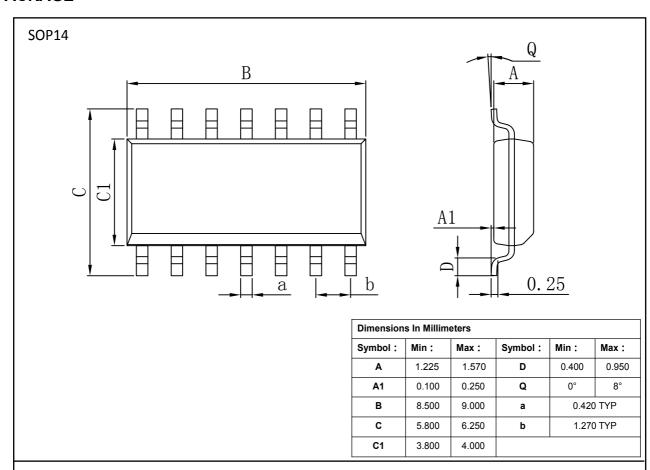




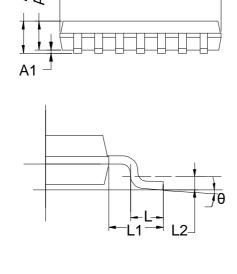
Dimension	Dimensions In Millimeters						
Symbol:	Min:	Max:	Symbol:	Min:	Max:		
Α	1.050	1.150	D	0.300	0.600		
A1	0.000	0.100	Q	0°	8°		
В	2.820	3.020	а	0.400 TYP			
С	2.650	2.950	b	0.950 TYP			
C1	1.500	1.700	е	1.900	) TYP		



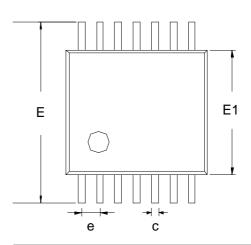
### **PACKAGE**







D



Dimensions In Millimeters							
Symbol :	Min:	Max:	Symbol :	Min:	Max:		
Α	0.950	1.200	E1	4.300	4.500		
A1	0.050	0.150	L	0.450	0.750		
A2	0.800	1.000	θ	0°	8°		
В	0.200	0.280	е	0.650	BSC		
С	0.100	0.190	L1	1.000	REF		
D	4.860	5.060	L2	1.250	BSC		
E	6.200	6.600					



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